CYPRESS SEMICONDUCTOR INVENTION DISCLOSURE FORM

DISCLOSURE NO. IC99001

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2. TITLE	OF IN	VENTION:	DECREASING				ING A
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4.	CONSTRUCTION OF DEVICE	
	A. Date completed B. Was prototype made? C. By whom made? D. Were can the prototype be found?	
5.	TEST OF DEVICE	У
٠.	TEST OF DEVICE	
		Kuang-Yu Chen
	B. Results: Successful	
6.	SALE	
	 A. Was invention sold or offered for sale? Yes NoX B. Was invention used to make, assemble or test a commercial product? Yes X C. Will invention be sold, offered for sale, sampled, or used to make, assem Yes X D. Actual or estimated date of first sale, offer or commercial use E. Is invention part of a product for which there is a data sheet? Yes X attach a copy of the data sheet) F. Actual or estimated date of publication, release or availability of data sheet? 	nble or test a commercial product? No (if yes,
7.	USE	
0	A. Is invention presently being used? Yes No	in the family
0.	RELATED PUBLICATIONS, PATENTS, AND PATENT A	APPLICATIONS
9.	WAS INVENTION: Conceived (Yes X (No Constructed (Yes (No during performance of Government Contract?	s X (No Tested (Yes X
Inve	entor(s) 12 - The Sh-	2/ /22
	W 44 01 -	Date 7/30/99
Inve	entor(s)	Date
Inve	entor(s) Albert then	Date
Wit	nessed, Read, and Understood by:	Date
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	Contract Number
	(Give Full Contract Number)
giv inv	e description of invention should be written in the inventor's own words and generally should follow the outline cen below. Sketches, prints, photos, and other illustrations, as well as memos or reports of any nature in which the cention is referred to, if available, should form a part of this disclosure and reference and be made thereto in the accriptions of the invention's construction and operation.
	OR ANSWERS TO THE FOLLOWING QUESTIONS, USE THE REMAINDER OF IEET AND THE ATTACHED SHEET(S).
1.	General purpose of invention. State in general terms the objects of the invention.
	To decrease the overshoot or undershoot in a PLL's frequency during the turn on or turn off of spread spectrum. This invention solves unpredictable transition period which could cause a CPU to hang when the spread spectrum transitions on or off.
2.	Describe old technology, if any, for performing the function of the invention. Provide references, if available.
	This problem has never been solved.
3.	Indicated the disadvantages of the old technology.
	No solution has been considered to spread spectrum transition behavior. Most of time, the transition happens unpredictably. Now it is controllable by programming and circuitry
4.	Describe your invention and its construction, showing the changes, additions and improvements over the old method.
Inv	entor(s) $\frac{\sqrt{3} - 7 \ln \sqrt{3}}{\ln \sqrt{3} - \sqrt{3}}$ entor(s) $\frac{\sqrt{3} - \sqrt{9}}{\ln \sqrt{3} - \sqrt{3}}$ entor(s) $\frac{\sqrt{3} - \sqrt{9}}{\ln \sqrt{3}}$ Date $\frac{\sqrt{3} - \sqrt{9}}{\sqrt{3}}$ entor(s) $\frac{\sqrt{3} - \sqrt{9}}{\ln \sqrt{3}}$ Date $\frac{\sqrt{3} - \sqrt{9}}{\sqrt{3}}$ nessed, Read, and Understood by: $\frac{\sqrt{3} - \sqrt{9}}{\ln \sqrt{3}}$
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Document No. 27-00030 Rev. *C

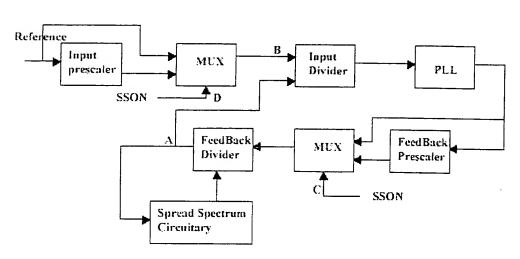
(Each page upon which information is entered should be signed and witnessed.)



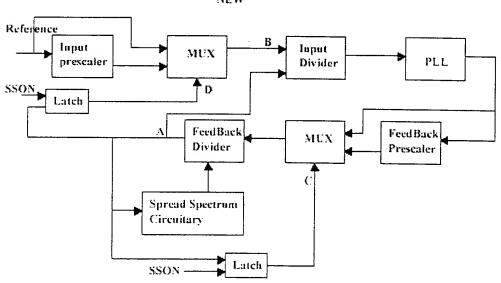
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1. Schematic

OLD



NEW

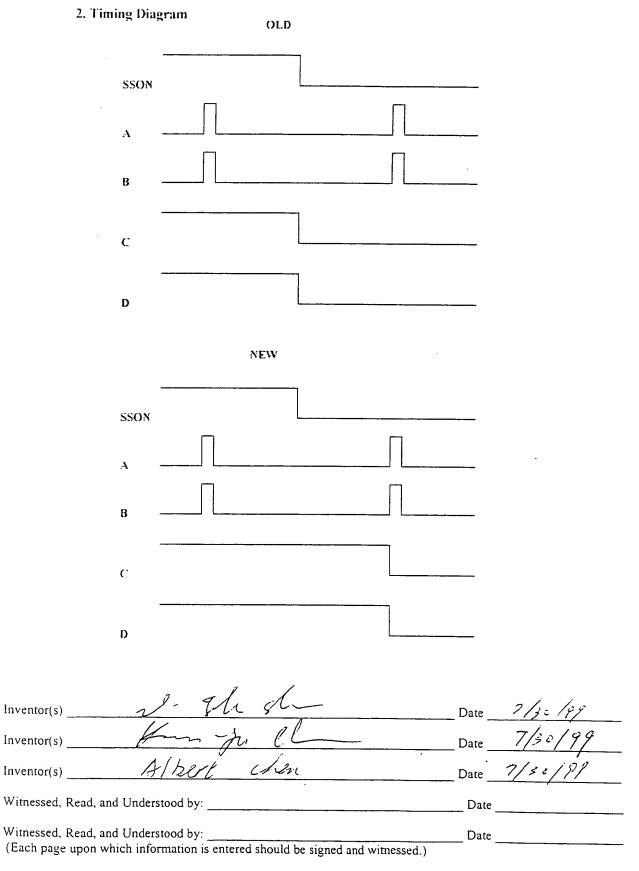


Inventor(s) 1- 7sh 8h	Date	1/3-199
Inventor(s) fr el-	Date	7/30/99
Inventor(s) Albert Chen	Date	7/30/88
Witnessed, Read, and Understood by:	Date _	
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3. Formula

A. Using the following formula to generate Spread Spectrum ROM code

$$\begin{bmatrix} X_{i}(N+1) \\ X_{2}(N+1) \end{bmatrix} = \begin{bmatrix} 0 & -\frac{VCO}{FBD(N+1)} & 0 \\ \frac{CP}{C_{i}} & \frac{1}{C_{i} \cdot R_{i}} & -\frac{1}{C_{i} \cdot R_{i}} \\ 0 & \frac{1}{C_{2} \cdot R_{i}} & \frac{1}{C_{2} \cdot R_{i}} \end{bmatrix} \begin{bmatrix} X_{i}(N) \\ X_{2}(N) \\ X_{3}(N) \end{bmatrix} * M(N) + \begin{bmatrix} U_{i}(N+1) \\ U_{i}(N+1) \end{bmatrix} * M(N) + \begin{bmatrix} X_{i}(N) \\ X_{3}(N) \end{bmatrix}$$

R=40 k at SSCG off R=24 k at SSCG on U(N) is changed when SSCG switches OFF-ON or ON-OFF

B. Input FBD(N) to PLL's transient program that optimize the FBD(N) order in ROM address.

C.

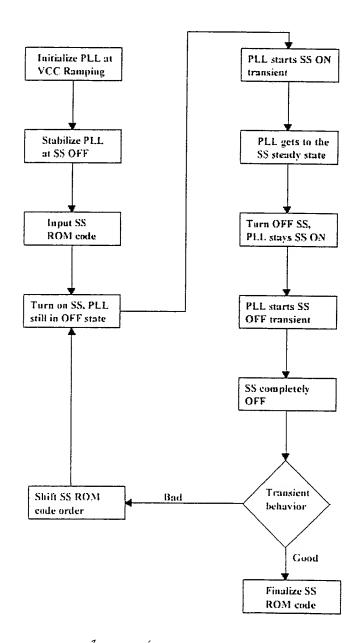
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Inventor(s)	Date	7/30/99
Inventor(s) Albert chen	Date	7/30/98
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4.



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Inventor(s) Long. Cl	_ Date	7/30/99
Inventor(s) Albert Chen	_ Date	7/30/98
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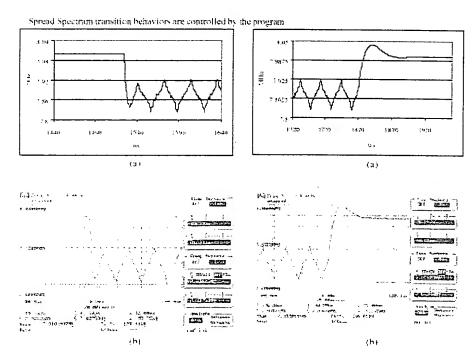


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5. Simulated and measured results



PLL's undershoot and overshoot behavior in spread spectrum transation



(a) Simulation (b) Measured results in off-in transition (a) Simulation (b) Measured results in on-off transition

Inventor(s) 1 - Wh The	Date	2/30/89
Inventor(s)	Date	7/30/99
Inventor(s) Albert Chen	Date	7/30/99
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5.	Give details of its operation (i.e., how is your invention used?), if not already described under 4.
6.	State the advantages of your invention over what has been done before.
	The transient behavior of a spread spectrum can be fully controllable. It prevents PLL's overshoot or undershoot from switching ss on or ss off.
7.	Indicated any alternate component(s) and/or method(s) of construction.
8.	If a joint invention, indicate what contribution was made by each inventor.
٠.	I-Teh Sha Implement pli's steady state and transition model The concept of ROM code Shifting to improve SSCG'S Kuang-Yu Chen Albert Chen Synchronized circuitry and layout implement
	Kuang-Yu Chen transition behavior
	Albert Chen Synchronized circuitry and layout implemen
9.	Describe the features that are believed to be new.
	 FORTRAN program is used to determine transient and steady-state spread spectrum behavior. All dividers and prescalers are synchronized. Transient behavior is simulated starting from steady-state condition
10.	State opinion of relative value of invention.
	This invention will apply to most of the existing spread spectrum devices. For spread spectrum applications, all EMI reduction chips need to add this invention in order to avoid CPU clock tracking failure during spread spectrum on-off or off-on transition.
11.	After the disclosure is prepared, it should be signed by the inventor(s) and then read and signed by two witnesses in the space provided at the bottom of each sheet.
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Inve	entor(s)
lnve	entor(s) $\int \int \int$
Inve	entor(s) Albert Chen Date 7/30/88
Witi	nessed. Read, and Understood by

Witnessed, Read, and Understood by: (Each page upon which information is entered should be signed and witnessed.)

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